MCH3477

Power MOSFET 20V, $38m\Omega$, 4.5A, Single N-Channel



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Features

- High Speed Switching
- 1.8V Drive
- ESD Diode-Protected Gate
- Low On-Resistance
- Pb-Free, Halogen Free and RoHS Compliance

VDSS	R _{DS} (on) Max	ID Max
	38 mΩ@4.5V	
20V	61 mΩ@2.5V	4.5A
	99 mΩ@1.8V	

Specifications

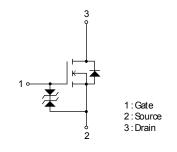
Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Value	Unit
Drain to Source Voltage	V _{DSS}	20	٧
Gate to Source Voltage	VGSS	±12	>
Drain Current (DC)	ID	4.5	Α
Drain Current (Pulse) PW≤10μs, duty cycle≤1%	I _{DP}	18	Α
Power Dissipation When mounted on ceramic substrate (900mm²×0.8mm)	PD	1.0	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	–55 to +150	°C

Thermal Resistance Ratings

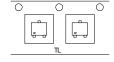
Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (900mm²×0.8mm)	$R_{ heta JA}$	125	°C/W

Electrical Connection N-Channel



Packing Type:TL

Marking





Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

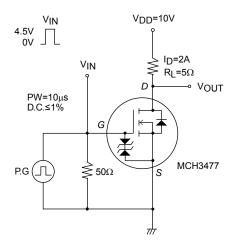
MCH3477

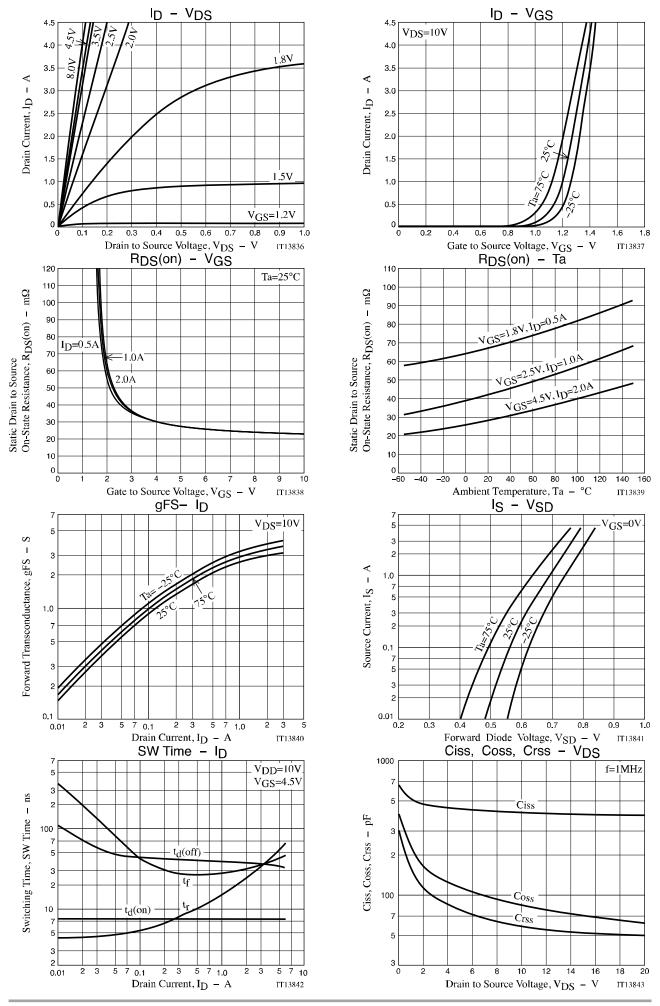
Electrical Characteristics at Ta = 25°C

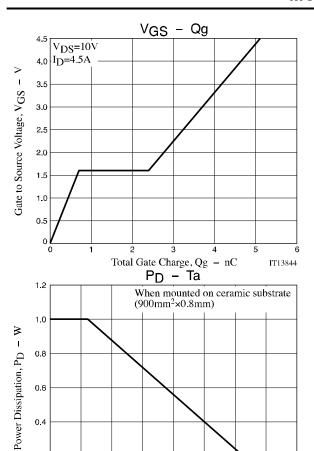
Parameter	Symbol	0 1111	Value			11.2
		Conditions	min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μΑ
Gate to Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Gate Threshold Voltage	V _{GS} (th)	V _{DS} =10V, I _D =1mA	0.4		1.3	٧
Forward Transconductance	9FS	V _{DS} =10V, I _D =2A	2.0	3.4		S
	R _{DS} (on)1	I _D =2A, V _{GS} =4.5V		29	38	mΩ
Static Drain to Source On-State Resistance	R _{DS} (on)2	I _D =1A, V _{GS} =2.5V		43	61	mΩ
	R _{DS} (on)3	I _D =0.5A, V _{GS} =1.8V		69	99	mΩ
Input Capacitance	Ciss			410		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		84		pF
Reverse Transfer Capacitance	Crss			59		pF
Turn-ON Delay Time	t _d (on)			7.5		ns
Rise Time	t _r	On a serifical Total Otto II		26		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		38		ns
Fall Time	tf			32		ns
Total Gate Charge	Qg			5.1		nC
Gate to Source Charge	Qgs	V _{DS} =10V, V _{GS} =4.5V, I _D =4.5A		0.7		nC
Gate to Drain "Miller" Charge	Qgd	7		1.7		nC
Forward Diode Voltage	V _{SD}	I _S =4.5A, V _{GS} =0V		0.78	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit

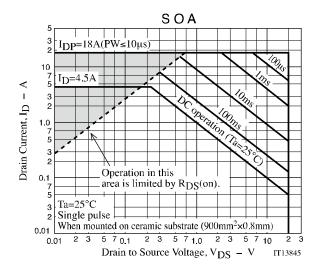


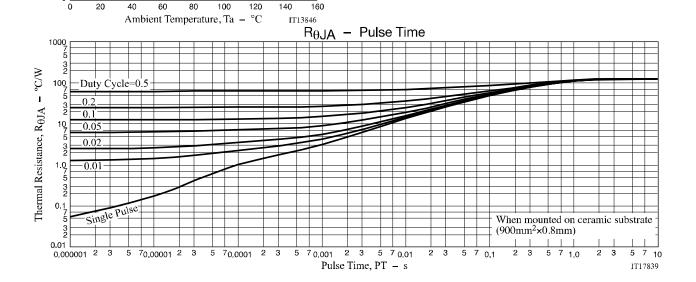




0.2

0 0





140

Package Dimensions

MCH3477-TL-H / MCH3477-TL-W

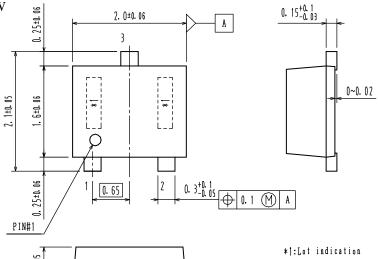
MCPH3

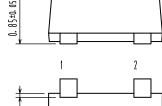
CASE 419AQ **ISSUE O**

Unit: mm

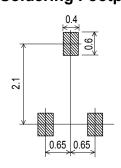
1: Gate 2: Source

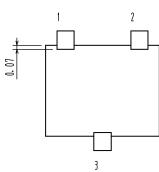
3: Drain





Recommended Soldering Footprint





ORDERING INFORMATION

Device	Package	Shipping	Note	
MCH3477-TL-H	MCPH3	3,000 pcs. / reel	Pb-Free	
MCH3477-TL-W	3477-TL-W SC-70,SOT-323		and Halogen Free	

Note on usage: Since the MCH3477 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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